

BIPOLAR ANALOG INTEGRATED CIRCUIT

23.7MAX3 VOLTAGE INPUT ADJ. PNP BRIGHT AL

 μ PC1308V**18 W AF POWER AMPLIFIER
SILICON BIPOLAR MONOLITHIC INTEGRATED CIRCUIT****DESCRIPTION**

The μ PC1308V is an audio power amplifier in a 14-lead vertical dual in-line package, specifically designed for car stereo applications.

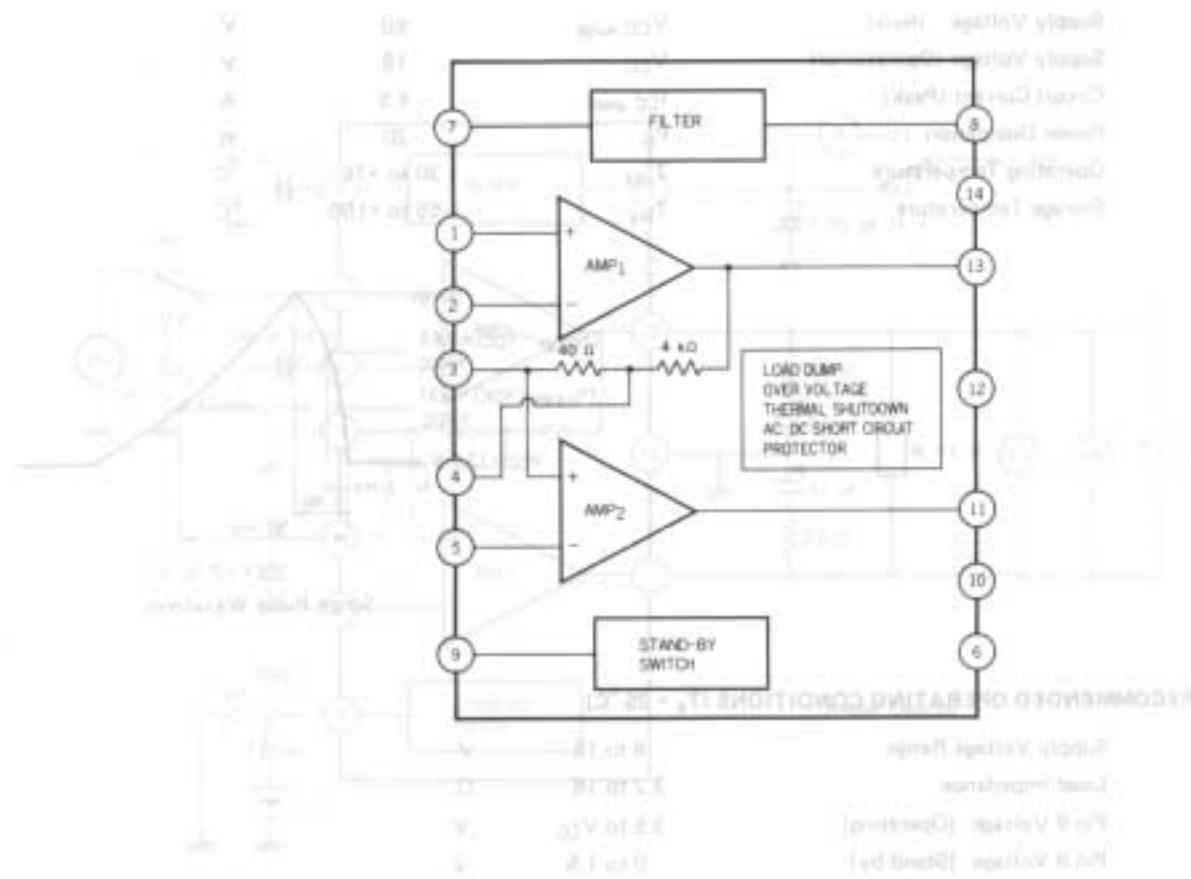
Typically it provides output power of 18 W at 14.4 V or 15 W at 13.2 V to a $4\ \Omega$ load.

This IC can be used without output capacitors, because its two output terminals have the same potential and it includes an original short circuit protection function which protects internal output power transistors and a speaker at the same time when one output terminal is shorted to ground.

FEATURES

- Internal stand-by switch circuit; CMOS drive possible.
- Can be used as OCL connection.
- Very low output offset voltage : $V_{offset} = 150\text{ mV}$ (MAX.)
- High output power : $P_O = 18\text{ W}$ (TYP.) @ $R_L = 4\ \Omega$, $V_{CC} = 14.4\text{ V}$, THD = 10 %
 $P_O = 15\text{ W}$ (TYP.) @ $R_L = 4\ \Omega$, $V_{CC} = 13.2\text{ V}$, THD = 10 %
- Very low distortion : THD = 0.1 % (TYP.)
- Following protection circuits are included.
 - (1) Load dump voltage surge protection circuit.
 - (2) Thermal shut down protection circuit.
 - (3) Output terminal short circuit protection circuit. (V_{CC} to OUT, OUT to GND, OUT to OUT)
 - (4) Loudspeaker protection circuit.

TEST BLOCK DIAGRAM



CONNECTION DIAGRAM

Tableau test WCO 5 pinout_1308V-1-138-1-8_VCC = 20V 3° 85 °C SOUTIENSTARAHJ JAJINTZSJA

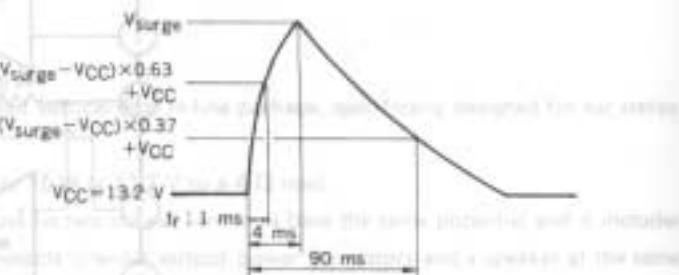
POSITION TEST SWITCH POSITION	TEST	V _{CC}	IN	OUT	TEST	TEST
1 - 2						
1 + 2 + 3 + 4 + 5 + 6 + 7 + 8						
1 + 2 + 3 + 4 + 5 + 6 + 7						
1 + 2 + 3 + 4 + 5 + 6						
1 + 2 + 3 + 4 + 5						
1 + 2 + 3 + 4						
1 + 2 + 3						
1 + 2						
1						
PIN No.	CONNECTION	PIN No.	CONNECTION			
1	Input 1	8	V _{CC}			
2	NFB 1	9	Stand-by switch			
3	GND (Input)	10	NC			
4	Output 1 Devided	11	Output 2			
5	NFB 2	12	GND (Output)			
6	GND (Output)	13	Output 1			
7	Filter	14	NC			

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Supply Voltage (Note)	$V_{CC \text{ surge}}$	60	V
Supply Voltage (Operational)	V_{CC}	18	V
Circuit Current (Peak)	$I_{CC \text{ peak}}$	4.5	A
Power Dissipation	P_D	20	W
Operating Temperature	T_{opt}	-30 to +75	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

SPECIFICATIONS

The μ PC1308V is a monolithic integrated circuit designed for audio power amplifiers. It features a high output power of 20 W into a 4 Ω load at 1 kHz, THD = 10%. The IC has been designed with a unique feedback network which provides a very low distortion and a wide frequency response. The circuit is fully balanced and can be easily interfaced with most standard audio components.



Surge Pulse Waveform

FEATURES

- Monolithic integrated circuit
- High output power: 20 W into 4 Ω , THD = 10% at 1 kHz

RECOMMENDED OPERATING CONDITIONS ($T_a = 25^\circ\text{C}$)

- Supply Voltage Range: 9 to 16 V
- Load Impedance: $R_L = 4 \Omega$, THD = 10% at 1 kHz
- Pin 9 Voltage (Operating): 3.5 to V_{CC} , THD = 10% at 1 kHz
- Pin 9 Voltage (Stand-by): 0 to 1.5 V
- Following connection circuits are recommended.

CONNECTION DIAGRAM

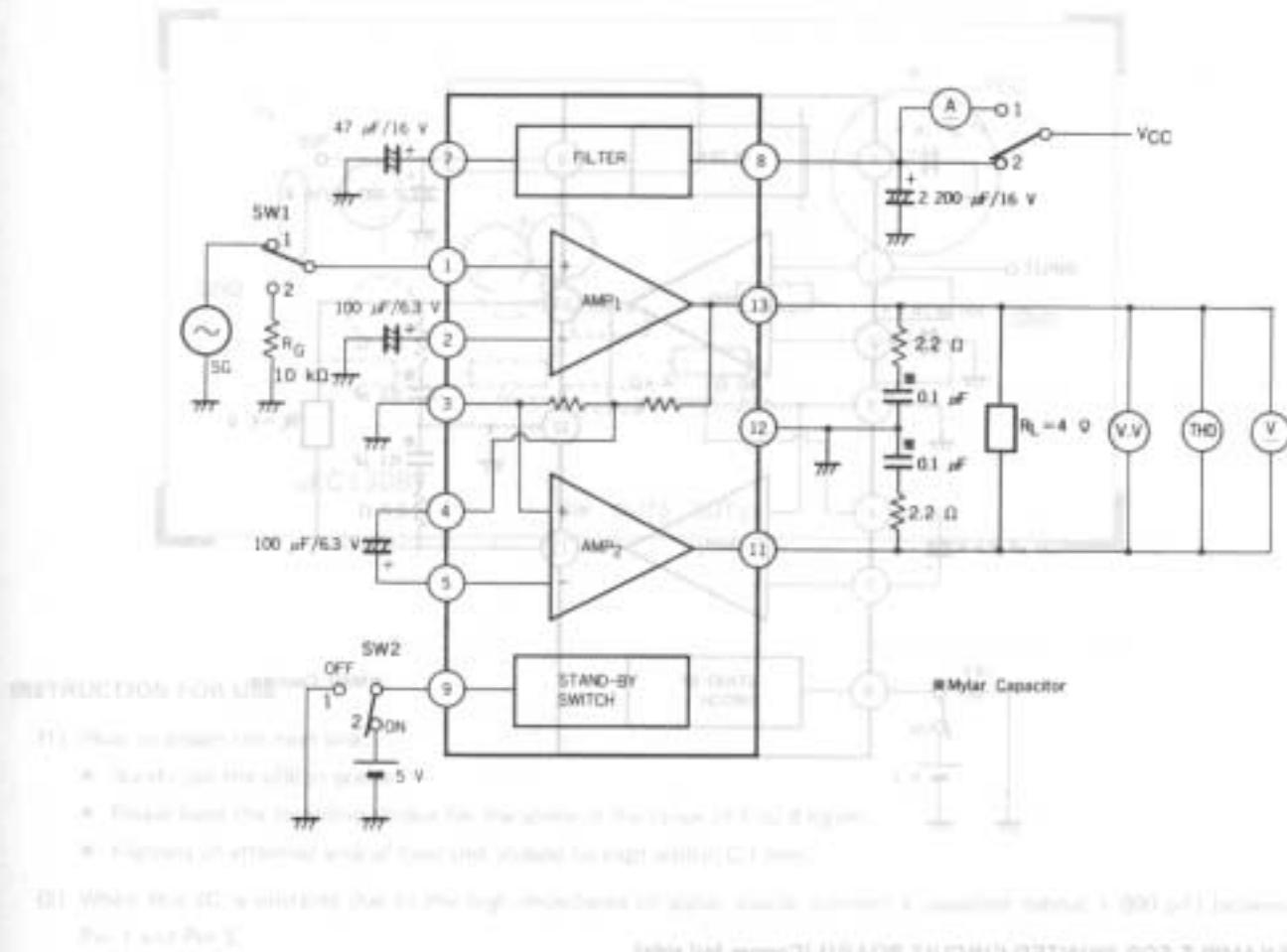
ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$, $V_{CC} = 13.2$ V, $R_L = 4 \Omega$, $f = 1$ kHz, Using 4 $^\circ\text{C}/\text{W}$ heat sink)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Quiescent Current	I_{CC}		90	150	mA	$V_I = 0$
Output Offset Voltage	V_{offset}		0	± 150	mV	$V_I = 0$
Output Power	P_D		18		W	$V_{CC} = 14.4$ V, THD = 10 %**
			12	15	W	$V_{CC} = 13.2$ V, THD = 10 %**
Voltage Gain	A_V	44	46	48	dB	
Total Harmonic Distortion	THD	0.1	0.5		%	$P_D = 1$ W
Output Noise Level	V_n	0.45	1.5		$\text{mV}_{\text{r.m.s.}}$	$R_G = 10$ k Ω , BW = 20 Hz to 20 kHz
Supply Voltage Rejection Ratio	SVR	40	46		dB	$R_G = 0$, $f_{rip} = 100$ Hz, $V_{rip} = 0.5$ V
Input Resistance	R_I	45	65		k Ω	
Roll-off Frequency	f_H		80		kHz	$A_V = -3$ dB from 1 kHz Ref. High
	f_L		10		Hz	$A_V = -3$ dB from 1 kHz Ref. Low
Stand-by Current	$I_{CC(\text{SB})}$		0.32	0.5	mA	$0 \leq V_g \leq 1.5$ V

(**Using a Voltmeter: HP-400FL)

CIRCUIT TEST CIRCUIT

NOTADUMA JAHYET



In this test mode the THD figure quoted for 1W MAX

SWITCH POSITION

5

CHARACTERISTIC	SYMBOL	SW 1	SW 2	SW 3
Quiescent Current	I_{CC}	2	2	1
Output Offset Voltage	V_{offset}	2	2	2
Voltage Gain	A_V	1	2	2
Output Power	P_O	1	2	2
Total Harmonic Distortion	THD	1	2	2
Output Noise Level	V_n	2	2	2
Stand-by Current	$I_{CC(SB)}$	1	1	1

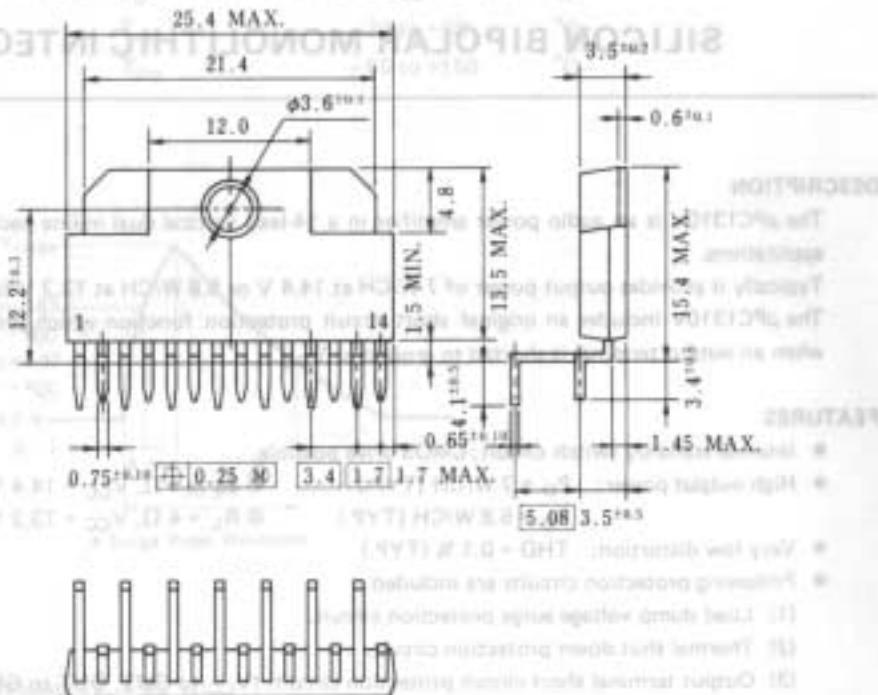
BIPOLEAR ANALOG INTEGRATED CIRCUIT

14 PIN V-DIP PACKAGE DIMENSIONS (Unit : mm)

μPC1308V
Gullwing Type DIP

Solder Soldering Lead

Power Generation

SILICON BIPOLEAR MONOLITHIC INTEGRATED CIRCUIT
2 W DUAL AF POWER AMPLIFIER

RECOMMENDED OPERATING CONDITIONS

Supply Voltage Range

V_{CC} = 12.0

mA

Input Frequency

MARDALIN CONNECTION

BLOCK DIAGRAM

Electrical Characteristics	Symbol	Min	Max
Supply Current	I _{CC}	1.0	1.5
Supply Voltage	V _{CC}	12.0	15.0
Output Power	P _{out}	2.0	2.0
Output Frequency	f _{out}	20	100
Output Impedance	Z _{out}	100	100
Output Gain	G _{out}	10	10
Output Noise	N _{out}	10	10
Output Distortion	D _{out}	10	10
Output Efficiency	η _{out}	10	10
Output Power	P _{out}	2.0	2.0
Output Frequency	f _{out}	20	100
Output Impedance	Z _{out}	100	100
Output Gain	G _{out}	10	10
Output Noise	N _{out}	10	10
Output Distortion	D _{out}	10	10
Output Efficiency	η _{out}	10	10
Output Power	P _{out}	2.0	2.0
Output Frequency	f _{out}	20	100
Output Impedance	Z _{out}	100	100
Output Gain	G _{out}	10	10
Output Noise	N _{out}	10	10
Output Distortion	D _{out}	10	10
Output Efficiency	η _{out}	10	10

